

Problem 1: Determine the region of operation (*e.g.*, Cutoff, Linear, Blown-up, Triode, Ohmic, Resistive, Saturation, Forward-Active, Reverse-Active, etc.) for each transistor below. For the NMOS and PMOS transistors, assume: $L = 0.1\mu\text{m}$, $W = 1.2\mu\text{m}$, $|V_{t0}| = 0.4\text{V}$, $|\gamma| = 0.4\text{V}^{0.5}$, $\phi_f = 0.3\text{V}$, $\mathcal{E}_c = 1.5 \times 10^6\text{V/m}$, and $\mu C_{OX} = 200\mu\text{A/V}^2$.

